

The Open University of Sri Lanka
Faculty of Engineering Technology
Department of Electrical & Computer Engineering



Study Programme	: Bachelor of Technology Honours in Engineering
Name of the Examination	: Final Examination
Course Code and Title	: EEX6550 Analog Electronic Systems
Academic Year	: 2020/2021
Date	: 22 nd February 2022
Time	: 0930-1230hrs
Duration	: 3 hours

General Instructions

1. Read all instructions carefully before answering the questions.
 2. This question paper consists of **Seven (7)** questions in **Five (5)** pages.
 3. Answer **only Five (5)** the questions.
 4. Answer for each question should commence from a new page.
 5. Relevant charts / codes are provided.
 6. This is a Closed Book Test (**CBT**).
 7. Answers should be in clear hand writing.
 8. Do not use red colour pens.
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Q1. Let the transistor in the amplifier circuit in Figure-Q1 has the following parameters with the usual notation.

$$g_m = 3.2\text{mS}, r_d = 100\text{k}\Omega, C_{gs} = 4\text{pF}, C_{ds} = 0.5\text{pF} \text{ and } C_{gd} = 1.2\text{pF}.$$

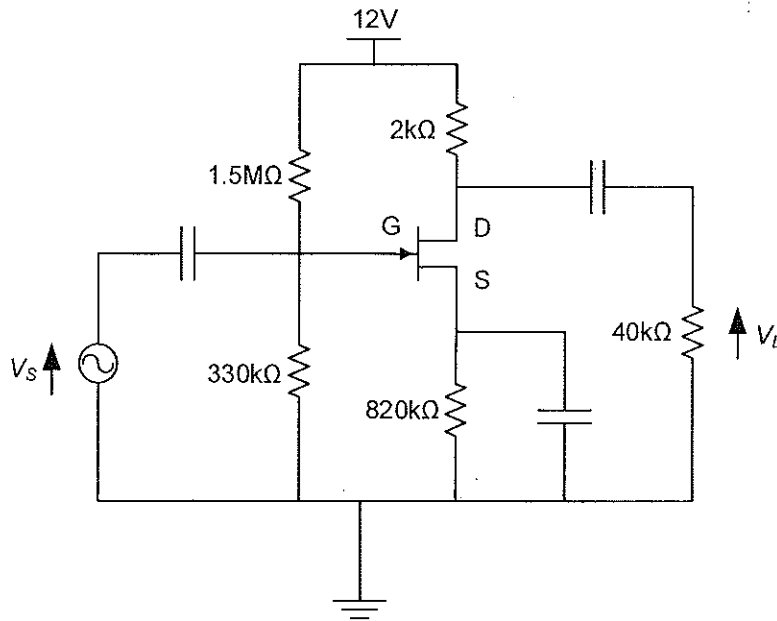


Figure-Q1

- (a) Draw the high frequency equivalent circuit for this amplifier circuit. **(6 Marks)**
- (b) Calculate the input and output impedances. **(8 Marks)**
- (c) Find the mid-band voltage gain of this amplifier. **(6 Marks)**
- Q2. Let the transistor in the amplifier circuit in Figure-Q2 has the following parameters with the usual notation. $r_{be} = 1\text{k}\Omega$, $r_{ce} = 80\text{k}\Omega$, $c_{bc} = 3\text{pF}$, $c_{be} = 100\text{pF}$ and $g_m = 50\text{mA}\text{V}^{-1}$. Assume the effect of all the other unmentioned parameters to be negligible.
- (a) Draw the high frequency hybrid- π equivalent circuit for this amplifier circuit. **(6Marks)**
- (b) Using Miller's theorem, simplify the equivalent circuit model. **(6Marks)**
- (c) Hence, find the voltage gain of the same amplifier. **(8Marks)**

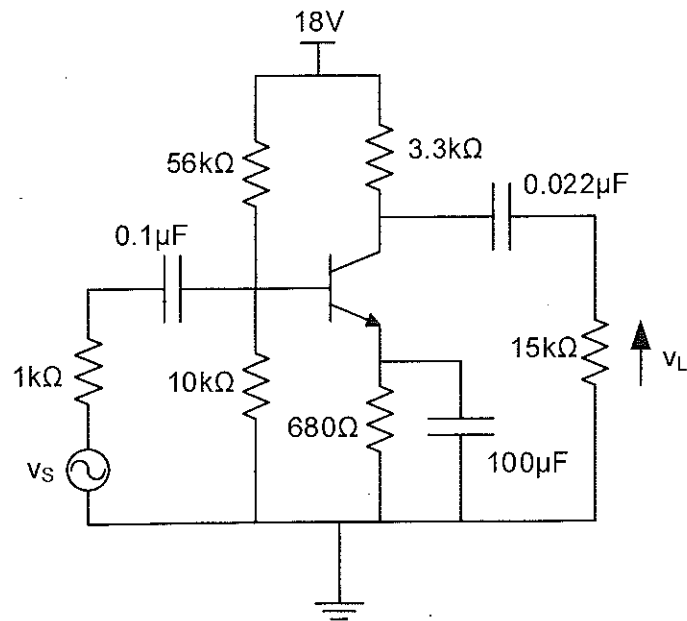


Figure-Q2

Q3. Consider the circuit in the Figure-Q3.

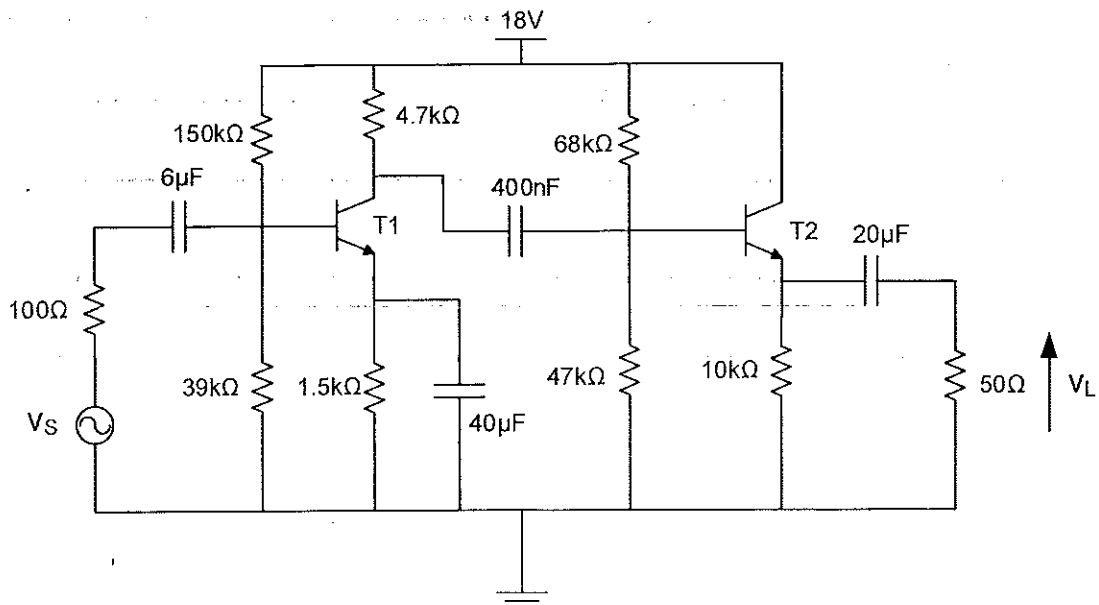


Figure-Q3

$$T1: h_{ie} = 1.4k\Omega, h_{re} = 2 \times 10^{-4}, h_{fe} = 180$$

$$T2: h_{ic} = 2k\Omega, h_{rc} = 1, h_{fc} = -101$$

(a) Draw the low frequency equivalent circuit.

(6 Marks)

Hence find,

- (b) Input impedance.
 (c) Output impedance.
 (d) Mid band voltage gain $\frac{V_L}{V_S}$.

(4 Marks)
 (2 Marks)
 (8 Marks)

Q4.

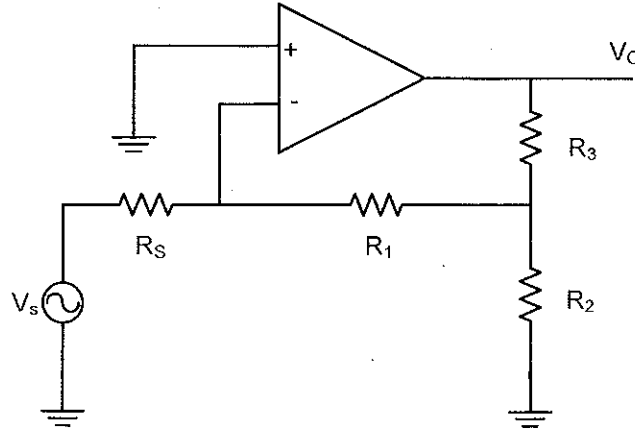


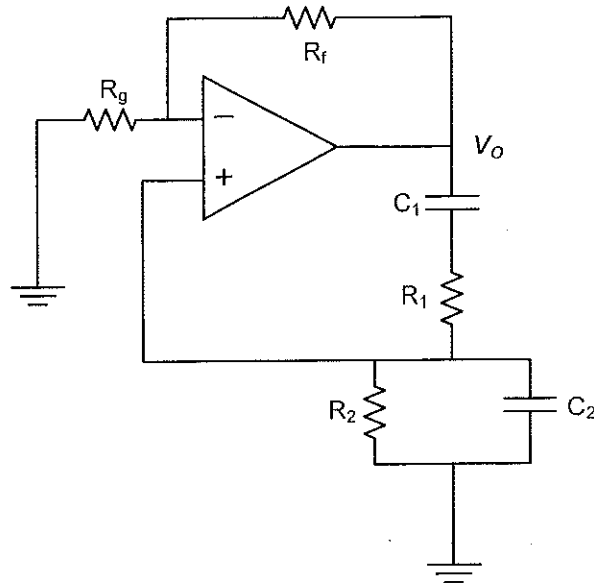
Figure -Q4

Consider the feed-back arrangement in the above Figure-Q4 circuit diagram. Let the open loop gain of the op-amp be 10,000.

$$R_1 = R_3 = R_S = 1k\Omega, R_2 = 100k\Omega.$$

- (a) Identify the type of feed-back used. (2 Marks)
 (b) Calculate the feedback factor, considering the effect of the input resistance. (8 Marks)
 (c) Let the amplifier is connected with a load $R_L = 1k\Omega$. Calculate the total closed-loop gain considering the effects of load and input resistances. (10Marks)

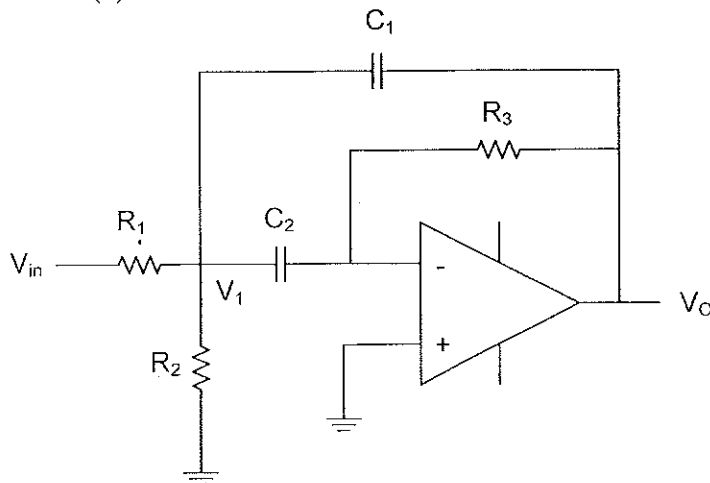
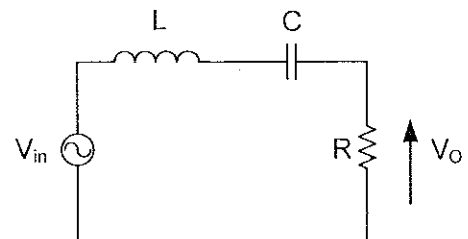
Q5.

**Figure-Q5**

- (a) Starting from the first principles, derive the Barkhausen criteria for oscillations to occur. **(4 Marks)**
- (b) Stating all your assumptions, derive an expression for the feedback factor for the circuit in Figure- Q5. **(8 Marks)**
- (c) Derive an expression for the forward gain. **(4 Marks)**
- (d) Hence find the frequency of oscillation. **(4 Marks)**

Q6.

- (a) List two commonly used filter transfer functions and their characteristics. **(4Marks)**
- (b)

**Figure Q6(a)****Figure Q6(b)**

- i. Derive the transfer function for the circuit in Figure Q6(a). **(8Marks)**
- ii. Show that the filter effects are the same for both circuits. **(4Marks)**
- iii. Find the expressions for the bandwidths of the two filter circuits. **(4Marks)**

Q7.

- (a) Using proper diagrams compare the ideal and practical diode characteristics. **(4 Marks)**
- (b) Consider the circuit diagram in Figure-Q7.

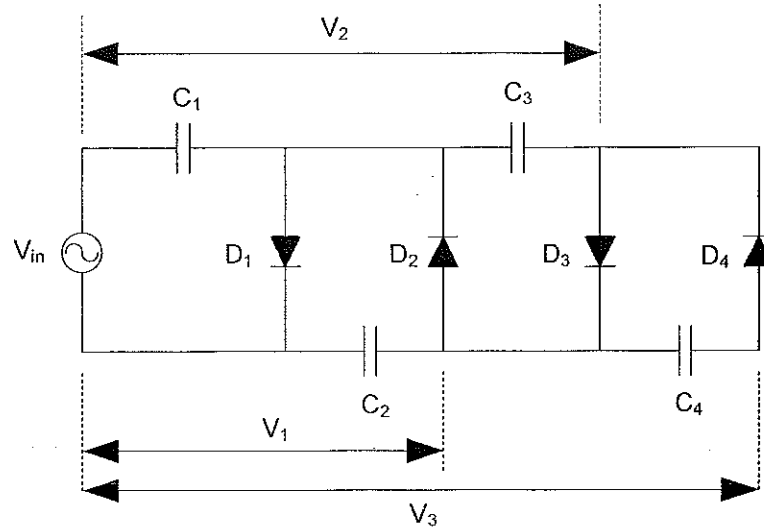


Figure-Q7

- i. Assuming ideal diode and capacitor behavior, explain the operation of the above circuit. **(4 Marks)**
- ii. Hence draw the waveforms of V_1, V_2 and V_3 for an input signal of $v_{in} = 10 \sin 20\pi t$. **(6 Marks)**
- iii. Draw the waveforms of V_1, V_2 and V_3 under non-ideal (practical) Si diode characteristics. **(6 Marks)**